

# Contents

<b>Abbreviations</b> .....	XXI
<b>Symbols</b> .....	XXVII
<b>Physical Constants</b> .....	XXXI
<b>1 Introduction</b> .....	1
1.1 Timetable .....	1
1.2 Nobel Prize Winners .....	7
1.3 General Information .....	9

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## Part I Fundamentals

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<b>2 Bonds</b> .....	15
2.1 Introduction .....	15
2.2 Covalent Bonds .....	15
2.2.1 Electron-Pair Bond .....	15
2.2.2 $sp^3$ Bond .....	15
2.2.3 $sp^2$ Bond .....	19
2.3 Ionic Bonds .....	21
2.4 Mixed Bond .....	23
2.5 Metallic Bond .....	25
2.6 van-der-Waals Bond .....	26
2.7 Hamilton Operator of the Solid .....	27
<b>3 Crystals</b> .....	29
3.1 Introduction .....	29
3.2 Crystal Structure .....	29
3.3 Lattice .....	30
3.3.1 Unit Cell .....	30
3.3.2 Point Group .....	31
3.3.3 Space Group .....	33
3.3.4 2D Bravais Lattices .....	34
3.3.5 3D Bravais Lattices .....	34
3.3.6 Polycrystalline Semiconductors .....	39

3.3.7	Amorphous Semiconductors .....	39
3.4	Important Crystal Structures .....	40
3.4.1	Rocksalt Structure .....	41
3.4.2	CsCl Structure .....	41
3.4.3	Diamond Structure .....	41
3.4.4	Zinblende Structure .....	42
3.4.5	Wurtzite Structure .....	43
3.4.6	Chalcopyrite Structure .....	45
3.4.7	Delafossite Structure .....	46
3.4.8	Perovskite Structure .....	48
3.4.9	NiAs Structure .....	48
3.5	Polytypism .....	48
3.6	Reciprocal Lattice .....	50
3.6.1	Reciprocal Lattice Vectors .....	51
3.6.2	Miller Indices .....	52
3.6.3	Brillouin Zone .....	54
3.7	Alloys .....	54
3.7.1	Random Alloys .....	55
3.7.2	Phase Diagram .....	57
3.7.3	Virtual Crystal Approximation .....	59
3.7.4	Lattice Parameter .....	59
3.7.5	Ordering .....	61
<b>4</b>	<b>Defects .....</b>	<b>63</b>
4.1	Introduction .....	63
4.2	Point Defects .....	63
4.3	Thermodynamics of Defects .....	65
4.4	Dislocations .....	67
4.5	Stacking Faults .....	71
4.6	Grain Boundaries .....	72
4.7	Antiphase and Inversion Domains .....	73
4.8	Disorder .....	76
<b>5</b>	<b>Mechanical Properties .....</b>	<b>77</b>
5.1	Introduction .....	77
5.2	Lattice Vibrations .....	77
5.2.1	Monoatomic Linear Chain .....	77
5.2.2	Diatomic Linear Chain .....	80
5.2.3	Lattice Vibrations of a Three-Dimensional Crystal .....	84
5.2.4	Phonons .....	86
5.2.5	Localized Vibrational Modes .....	87
5.2.6	Phonons in Alloys .....	89
5.2.7	Electric Field Created by Optical Phonons .....	91
5.3	Elasticity .....	94
5.3.1	Stress-Strain Relation .....	94

5.3.2	Biaxial Strain . . . . .	99
5.3.3	Three-Dimensional Strain . . . . .	100
5.3.4	Substrate Bending . . . . .	102
5.3.5	Scrolling . . . . .	103
5.3.6	Critical Thickness . . . . .	105
5.4	Cleaving . . . . .	109
<b>6</b>	<b>Band Structure . . . . .</b>	<b>111</b>
6.1	Introduction . . . . .	111
6.2	Bloch's Theorem . . . . .	111
6.3	Free-Electron Dispersion . . . . .	112
6.4	Kronig–Penney Model . . . . .	114
6.5	Electrons in a Periodic Potential . . . . .	116
6.5.1	Approximate Solution at the Zone Boundary . . . . .	117
6.5.2	Solution in the Vicinity of the Zone Boundary . . . . .	118
6.5.3	Kramer's degeneracy . . . . .	119
6.6	Band Structure of Selected Semiconductors . . . . .	119
6.6.1	Silicon . . . . .	119
6.6.2	Germanium . . . . .	119
6.6.3	GaAs . . . . .	119
6.6.4	GaP . . . . .	120
6.6.5	GaN . . . . .	120
6.6.6	Lead Salts . . . . .	121
6.6.7	Chalcopyrites . . . . .	122
6.6.8	Delafossites . . . . .	123
6.6.9	Perovskites . . . . .	123
6.7	Alloy Semiconductors . . . . .	124
6.8	Amorphous Semiconductors . . . . .	125
6.9	Systematics of Semiconductor Bandgaps . . . . .	125
6.10	Temperature Dependence of the Bandgap . . . . .	129
6.11	Equation of Electron Motion . . . . .	131
6.12	Electron Mass . . . . .	132
6.12.1	Effective Mass . . . . .	132
6.12.2	Polaron Mass . . . . .	135
6.12.3	Nonparabolicity of Electron Mass . . . . .	136
6.13	Holes . . . . .	136
6.13.1	Hole Concept . . . . .	136
6.13.2	Hole Dispersion Relation . . . . .	138
6.13.3	Valence-Band Fine Structure . . . . .	140
6.14	Strain Effect on the Band Structure . . . . .	142
6.14.1	Strain effect on Band Edges . . . . .	143
6.14.2	Strain Effect on Effective Masses . . . . .	144
6.15	Density of States . . . . .	144
6.15.1	General Band Structure . . . . .	144
6.15.2	Free-Electron Gas . . . . .	145

<b>7</b>	<b>Electronic Defect States</b> .....	149
7.1	Introduction .....	149
7.2	Fermi Distribution .....	149
7.3	Carrier Concentration .....	151
7.4	Intrinsic Conduction .....	153
7.5	Shallow Impurities, Doping .....	156
	7.5.1 Donors .....	157
	7.5.2 Acceptors .....	164
	7.5.3 Compensation .....	167
	7.5.4 Amphoteric Impurities .....	170
	7.5.5 High Doping .....	171
7.6	Quasi-Fermi Levels .....	174
7.7	Deep Levels .....	175
	7.7.1 Charge States .....	176
	7.7.2 Jahn–Teller Effect .....	177
	7.7.3 Negative- $U$ Center .....	178
	7.7.4 DX Center .....	180
	7.7.5 EL2 Defect .....	182
	7.7.6 Semi-insulating Semiconductors .....	183
	7.7.7 Surface States .....	184
7.8	Hydrogen in Semiconductors .....	185
<b>8</b>	<b>Transport</b> .....	189
8.1	Introduction .....	189
8.2	Conductivity .....	190
8.3	Low-Field Transport .....	191
	8.3.1 Mobility .....	191
	8.3.2 Microscopic Scattering Processes .....	192
	8.3.3 Ionized Impurity Scattering .....	193
	8.3.4 Deformation Potential Scattering .....	193
	8.3.5 Piezoelectric Potential Scattering .....	194
	8.3.6 Polar Optical Scattering .....	194
	8.3.7 Temperature Dependence .....	194
8.4	Hall Effect .....	197
8.5	High-Field Transport .....	200
	8.5.1 Drift-Saturation Velocity .....	200
	8.5.2 Velocity Overshoot .....	201
	8.5.3 Impact Ionization .....	202
8.6	High-Frequency Transport .....	205
8.7	Diffusion .....	205
8.8	Continuity Equation .....	206
8.9	Heat Conduction .....	207
8.10	Coupled Heat and Charge Transport .....	209
	8.10.1 Seebeck Effect .....	209
	8.10.2 Peltier Effect .....	210

<b>9</b>	<b>Optical Properties</b> .....	213
9.1	Spectral Regions and Overview .....	213
9.2	Reflection and Diffraction .....	214
9.3	Electron–Photon Interaction .....	216
9.4	Band–Band Transitions .....	219
9.4.1	Joint Density of States .....	219
9.4.2	Direct Transitions .....	219
9.4.3	Indirect Transitions .....	221
9.4.4	Urbach Tail .....	223
9.4.5	Intravalence-Band Absorption .....	225
9.4.6	Amorphous Semiconductors .....	225
9.4.7	Excitons .....	225
9.4.8	Exciton Polariton .....	229
9.4.9	Bound-Exciton Absorption .....	232
9.4.10	Biexcitons .....	234
9.4.11	Trions .....	235
9.4.12	Burstein–Moss Shift .....	235
9.4.13	Bandgap Renormalization .....	236
9.4.14	Electron–Hole Droplets .....	238
9.4.15	Two-Photon Absorption .....	239
9.5	Impurity Absorption .....	240
9.6	Free-Carrier Absorption .....	242
9.7	Lattice Absorption .....	245
9.7.1	Dielectric Constant .....	245
9.7.2	Reststrahlenbande .....	246
9.7.3	Polaritons .....	248
9.7.4	Phonon–Plasmon Coupling .....	249
<b>10</b>	<b>Recombination</b> .....	251
10.1	Introduction .....	251
10.2	Band–Band Recombination .....	251
10.2.1	Spontaneous Emission .....	251
10.2.2	Absorption .....	252
10.2.3	Stimulated Emission .....	253
10.2.4	Net Recombination Rate .....	253
10.2.5	Recombination Dynamics .....	254
10.2.6	Lasing .....	256
10.3	Free-Exciton Recombination .....	256
10.4	Bound-Exciton Recombination .....	258
10.5	Alloy Broadening .....	260
10.6	Phonon Replica .....	261
10.7	Donor–Acceptor Pair Transitions .....	265
10.8	Inner-Impurity Recombination .....	267
10.9	Auger Recombination .....	267
10.10	Band–Impurity Recombination .....	268

10.11	Field Effect	272
10.11.1	Thermally Activated Emission	272
10.11.2	Direct Tunneling	273
10.11.3	Assisted Tunneling	273
10.12	Multilevel Traps	273
10.13	Surface Recombination	274
10.14	Excess-Carrier Profiles	274
<b>11</b>	<b>Heterostructures</b>	<b>277</b>
11.1	Introduction	277
11.2	Growth Methods	277
11.3	Material Combinations	280
11.3.1	Pseudomorphic Structures	280
11.3.2	Heterosubstrates	280
11.4	Band Lineup in Heterostructures	285
11.5	Energy Levels in Heterostructures	286
11.5.1	Quantum Well	286
11.5.2	Superlattices	293
11.5.3	Single Heterointerface Between Doped Materials	293
11.6	Recombination in Quantum Wells	295
11.7	Isotope Superlattices	299
11.8	Wafer Bonding	300
<b>12</b>	<b>External Fields</b>	<b>303</b>
12.1	Electric Fields	303
12.1.1	Bulk Material	303
12.1.2	Quantum Wells	305
12.2	Magnetic Fields	306
12.2.1	Free-Carrier Absorption	307
12.2.2	Energy Levels in Bulk Crystals	308
12.2.3	Energy Levels in a 2DEG	309
12.2.4	Shubnikov–de Haas Oscillations	310
12.3	Quantum Hall Effect	313
12.3.1	Integral QHE	313
12.3.2	Fractional QHE	317
12.3.3	Weiss Oscillations	318
<b>13</b>	<b>Nanostructures</b>	<b>321</b>
13.1	Introduction	321
13.2	Quantum Wires	321
13.2.1	Preparation Methods	321
13.2.2	Quantization in Two-Dimensional Potential Wells	328
13.3	Quantum Dots	328
13.3.1	Quantization in Three-Dimensional Potential Wells	328

13.3.2	Electrical and Transport Properties . . . . .	331
13.3.3	Self-Assembled Preparation . . . . .	336
13.3.4	Optical Properties . . . . .	341
<b>14</b>	<b>Polarized Semiconductors . . . . .</b>	<b>345</b>
14.1	Introduction . . . . .	345
14.2	Spontaneous Polarization . . . . .	345
14.3	Ferroelectricity . . . . .	346
14.3.1	Materials . . . . .	348
14.3.2	Soft Phonon Mode . . . . .	348
14.3.3	Phase Transition . . . . .	348
14.3.4	Domains . . . . .	352
14.3.5	Optical Properties . . . . .	353
14.4	Piezoelectricity . . . . .	353
<b>15</b>	<b>Magnetic Semiconductors . . . . .</b>	<b>359</b>
15.1	Introduction . . . . .	359
15.2	Magnetic Semiconductors . . . . .	359
15.3	Diluted Magnetic Semiconductors . . . . .	361
15.4	Spintronics . . . . .	365
15.4.1	Spin Transistor . . . . .	366
15.4.2	Spin LED . . . . .	367
<b>16</b>	<b>Organic Semiconductors . . . . .</b>	<b>369</b>
16.1	Materials . . . . .	369
16.2	Properties . . . . .	371
<b>17</b>	<b>Dielectric Structures . . . . .</b>	<b>375</b>
17.1	Photonic-Bandgap Materials . . . . .	375
17.1.1	Introduction . . . . .	375
17.1.2	General 1D Scattering Theory . . . . .	375
17.1.3	Transmission of an $N$ -Period Potential . . . . .	377
17.1.4	The Quarter-Wave Stack . . . . .	379
17.1.5	Formation of a 3D Band Structure . . . . .	382
17.1.6	Defect Modes . . . . .	385
17.1.7	Coupling to an Electronic Resonance . . . . .	387
17.2	Microscopic Resonators . . . . .	390
17.2.1	Microdiscs . . . . .	390
17.2.2	Purcell Effect . . . . .	392
17.2.3	Deformed Resonators . . . . .	393
17.2.4	Hexagonal Cavities . . . . .	395

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**Part II Applications**


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<b>18</b>	<b>Diodes</b> .....	401
18.1	Introduction .....	401
18.2	Metal–Semiconductor Contacts .....	402
18.2.1	Band Diagram in Equilibrium .....	402
18.2.2	Space-Charge Region .....	407
18.2.3	Schottky Effect .....	409
18.2.4	Capacitance .....	410
18.2.5	Current–Voltage Characteristic .....	412
18.2.6	Ohmic Contacts .....	421
18.2.7	Metal Contacts to Organic Semiconductors .....	424
18.3	Metal–Insulator–Semiconductor Diodes .....	425
18.3.1	Band Diagram for Ideal MIS Diode .....	427
18.3.2	Space-Charge Region .....	428
18.3.3	Capacity .....	432
18.3.4	Nonideal MIS Diode .....	435
18.4	Bipolar Diodes .....	435
18.4.1	Band Diagram .....	436
18.4.2	Space-Charge Region .....	437
18.4.3	Capacitance .....	442
18.4.4	Current–Voltage Characteristics .....	443
18.4.5	Breakdown .....	454
18.5	Applications and Special Diode Devices .....	457
18.5.1	Rectification .....	457
18.5.2	Frequency Mixing .....	460
18.5.3	Voltage Regulator .....	462
18.5.4	Zener Diodes .....	463
18.5.5	Varactors .....	463
18.5.6	Fast-Recovery Diodes .....	466
18.5.7	Step-Recovery Diodes .....	466
18.5.8	pin-Diodes .....	468
18.5.9	Tunneling Diodes .....	469
18.5.10	Backward Diodes .....	471
18.5.11	Heterostructure Diodes .....	471
<b>19</b>	<b>Light-to-Electricity Conversion</b> .....	473
19.1	Photocatalysis .....	473
19.2	Photoconductors .....	475
19.2.1	Introduction .....	475
19.2.2	Photoconductivity Detectors .....	475
19.2.3	Electrophotography .....	477
19.2.4	QWIPs .....	477
19.2.5	Blocked Impurity-Band Detectors .....	482



19.3	Photodiodes . . . . .	484
19.3.1	Introduction . . . . .	484
19.3.2	pn Photodiodes . . . . .	484
19.3.3	pin Photodiodes . . . . .	487
19.3.4	Position-Sensing Detector . . . . .	489
19.3.5	MSM Photodiodes . . . . .	490
19.3.6	Avalanche Photodiodes . . . . .	495
19.3.7	Traveling-Wave Photodetectors . . . . .	498
19.3.8	Charge Coupled Devices . . . . .	501
19.3.9	Photodiode Arrays . . . . .	509
19.4	Solar Cells . . . . .	511
19.4.1	Solar Radiation . . . . .	511
19.4.2	Ideal Solar Cells . . . . .	513
19.4.3	Real Solar Cells . . . . .	516
19.4.4	Design Refinements . . . . .	516
19.4.5	Solar-Cell Types . . . . .	517
19.4.6	Commercial Issues . . . . .	520
<b>20</b>	<b>Electricity-to-Light Conversion . . . . .</b>	<b>523</b>
20.1	Radiometric and Photometric Quantities . . . . .	523
20.1.1	Radiometric Quantities . . . . .	523
20.1.2	Photometric Quantities . . . . .	523
20.2	Scintillators . . . . .	524
20.2.1	CIE Chromaticity Diagram . . . . .	525
20.2.2	Display Applications . . . . .	528
20.2.3	Radiation Detection . . . . .	528
20.2.4	Luminescence Mechanisms . . . . .	530
20.3	Light-Emitting Diodes . . . . .	531
20.3.1	Introduction . . . . .	531
20.3.2	Spectral Ranges . . . . .	531
20.3.3	Quantum Efficiency . . . . .	532
20.3.4	Device Design . . . . .	533
20.4	Lasers . . . . .	539
20.4.1	Introduction . . . . .	539
20.4.2	Applications . . . . .	542
20.4.3	Gain . . . . .	543
20.4.4	Optical Mode . . . . .	547
20.4.5	Loss Mechanisms . . . . .	552
20.4.6	Threshold . . . . .	554
20.4.7	Spontaneous Emission Factor . . . . .	555
20.4.8	Output Power . . . . .	555
20.4.9	Temperature Dependence . . . . .	559
20.4.10	Mode Spectrum . . . . .	560
20.4.11	Longitudinal Single-Mode Lasers . . . . .	560
20.4.12	Tunability . . . . .	562

XVIII Contents

20.4.13	Modulation . . . . .	564
20.4.14	Surface-emitting Lasers . . . . .	568
20.4.15	Optically Pumped Semiconductor Lasers . . . . .	571
20.4.16	Quantum Cascade Lasers . . . . .	573
20.4.17	Hot-Hole Lasers . . . . .	573
20.5	Semiconductor Optical Amplifiers . . . . .	575
<b>21</b>	<b>Transistors . . . . .</b>	<b>577</b>
21.1	Introduction . . . . .	577
21.2	Bipolar Transistors . . . . .	577
21.2.1	Carrier Density and Currents . . . . .	579
21.2.2	Current Amplification . . . . .	582
21.2.3	Ebers–Moll Model . . . . .	583
21.2.4	Current–Voltage Characteristics . . . . .	585
21.2.5	Basic Circuits . . . . .	588
21.2.6	High-Frequency Properties . . . . .	589
21.2.7	Heterobipolar Transistors . . . . .	590
21.2.8	Light-emitting Transistors . . . . .	590
21.3	Field-Effect Transistors . . . . .	592
21.4	JFET and MESFET . . . . .	593
21.4.1	General Principle . . . . .	593
21.4.2	Static Characteristics . . . . .	594
21.4.3	Normally On and Normally Off FETs . . . . .	597
21.4.4	Field-Dependent Mobility . . . . .	598
21.4.5	High-Frequency Properties . . . . .	601
21.5	MOSFETs . . . . .	601
21.5.1	Operation Principle . . . . .	601
21.5.2	Current–Voltage Characteristics . . . . .	602
21.5.3	MOSFET Types . . . . .	606
21.5.4	Complementary MOS . . . . .	608
21.5.5	Large-Scale Integration . . . . .	610
21.5.6	Nonvolatile Memories . . . . .	614
21.5.7	Heterojunction FETs . . . . .	615
21.6	Thin-Film Transistors . . . . .	619

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**Part III Appendices**

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<b>A</b>	<b>Tensors . . . . .</b>	<b>623</b>
<b>B</b>	<b>Kramers–Kronig Relations . . . . .</b>	<b>627</b>
<b>C</b>	<b>Oscillator Strength . . . . .</b>	<b>629</b>
<b>D</b>	<b>Quantum Statistics . . . . .</b>	<b>635</b>

<b>E</b>	<b>The <math>k \cdot p</math> Perturbation Theory</b> .....	639
<b>F</b>	<b>Effective-Mass Theory</b> .....	643
	<b>References</b> .....	645
	<b>Index</b> .....	669